# Four-Channel, Four-Quadrant Analog Multiplier 

## FEATURES

Four Independent Channels
Voltage IN, Voltage OUT
No Extemal Parts Required
8 MHz Bandwidth
Four-Quadrant Multiplication
Voltage Output; $\mathbf{W}=(\mathbf{X} \times \mathbf{Y}) / 2.5 \mathrm{~V}$
0.2\% Typical Linearity Error on X or $Y$ Inputs

Excellent Temperature Stability: 0.005\%
$\pm 2.5$ V Analog Input Range
Operates from $\pm 5 \mathrm{~V}$ Supplies
Low Power Dissipation: 150 mW typ
Spice Model Available

## APPLICATIONS <br> Geometry Correction in High-Resolution CRT Displays <br> Waveform Modulation \& Generation <br> Voltage Controlled Amplifiers <br> Automatic Gain Control <br> Modulation and Demodulation

## GENERAL DESCRIPTION

The M LT 04 is a complete, four-channel, voltage output analog multiplier packaged in an 18-pin DIP or SOIC-18. These complete multipliers are ideal for general purpose applications such as voltage controlled amplifiers, variable active filters, "zipper" noise free audio level adjustment, and automatic gain control. Other applications include cost-effective multiple-channel power calculations $(\mathrm{I} \times \mathrm{V})$, polynomial correction generation, and low frequency modulation. The M LT 04 multiplier is ideally suited for generating complex, high-order waveforms especially suitable for geometry correction in high-resolution CRT display systems.


Figure 1. Gain \& Phase vs. Frequency Response

## REV. B

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices.

FUNCTIONAL BLOCK DIAGRAM
18-Lead Epoxy DIP (P Suffix)
18-Lead Wide Body SOIC (S Suffix)


Fabricated in a complementary bipolar process, the M LT 04 includes four 4-quadrant multiplying cells which have been lasertrimmed for accuracy. A precision internal bandgap reference normalizes signal computation to a 0.4 scale factor. Drift over temperature is under $0.005 \% /{ }^{\circ} \mathrm{C}$. Spot noise voltage of $0.3 \mu \mathrm{~V} / \mathrm{VHz}$ results in a THD + N oise performance of $0.02 \%$ (LPF $=22 \mathrm{kHz}$ ) for the lower distortion $Y$ channel. T he four 8 M Hz channels consume a total of 150 mW of quiescent power.

The M LT 04 is available in 18-pin plastic DIP, and SOIC-18 surface mount packages. All parts are offered in the extended industrial temperature range $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+85^{\circ} \mathrm{C}\right)$.


Figure 2. THD + Noise vs. Frequency

# MLTO4- SPECIFICATONS <br> $\left(V_{C C}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5 \mathrm{~V}, \mathrm{~V}_{\mathrm{IN}}= \pm 2.5 \mathrm{~V}_{\mathrm{P}}, \mathrm{R}_{\mathrm{L}}=2 \mathrm{k} \Omega, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right.$ unless otherwise noted.) 

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MULTIPLIER PERFORMANCE ${ }^{1}$ <br> T otal Error ${ }^{2} \mathrm{X}$ <br> T otal Error ${ }^{2} Y$ <br> Linearity Error ${ }^{2} \mathrm{X}$ <br> Linearity Error ${ }^{2}$ Y <br> T otal Error D rift <br> T otal Error D rift <br> Scale F actor ${ }^{3}$ <br> Output Offset Voltage <br> Output Offset Drift <br> Offset Voltage, X <br> Offset Voltage, Y | $E_{x}$ $E_{Y}$ <br> LE <br> LE ${ }_{Y}$ <br> TCE ${ }_{x}$ <br> TCE ${ }_{Y}$ <br> K <br> $\mathrm{Z}_{0 \mathrm{~s}}$ <br> $T C Z_{\text {os }}$ <br> $X_{0 s}$ <br> $Y_{\text {os }}$ | $\begin{aligned} & -2.5 \mathrm{~V}<X<+2.5 \mathrm{~V}, Y=+2.5 \mathrm{~V} \\ & -2.5 \mathrm{~V}<Y<+2.5 \mathrm{~V}, \mathrm{X}=+2.5 \mathrm{~V} \\ & -2.5 \mathrm{~V}<X<+2.5 \mathrm{~V}, \mathrm{Y}=+2.5 \mathrm{~V} \\ & -2.5 \mathrm{~V}<Y<+2.5 \mathrm{~V}, \mathrm{X}=+2.5 \mathrm{~V} \\ & X=-2.5 \mathrm{~V}, Y=2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & Y=-2.5 \mathrm{~V}, X=2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & X= \pm 2.5 \mathrm{~V}, Y= \pm 2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & X=0 \mathrm{~V}, Y=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & X=0 \mathrm{~V}, Y=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & X=0 \mathrm{~V}, Y= \pm 2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \\ & Y=0 \mathrm{~V}, X= \pm 2.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{aligned}$ | $\begin{aligned} & -5 \\ & -5 \\ & -1 \\ & -1 \\ & \\ & 0.38 \\ & -50 \\ & \\ & -50 \\ & -50 \end{aligned}$ | $\begin{aligned} & \pm 2 \\ & \pm 2 \\ & \pm 0.2 \\ & \pm 0.2 \\ & 0.005 \\ & 0.005 \\ & 0.40 \\ & \pm 10 \\ & 50 \\ & \pm 10.5 \\ & \pm 10.5 \end{aligned}$ | $\begin{aligned} & 5 \\ & 5 \\ & +1 \\ & +1 \\ & \\ & 0.42 \\ & 50 \\ & 50 \\ & 50 \end{aligned}$ | \% FS \% FS \% FS \% FS $\% /{ }^{\circ} \mathrm{C}$ $\% /{ }^{\circ} \mathrm{C}$ 1/N mV $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ mV mV |
| DYNAMIC PERFORMANCE <br> Small Signal Bandwidth <br> Slew Rate Settling Time AC F eedthrough Crosstalk @ 100 kHz | $\begin{aligned} & \mathrm{BW} \\ & \mathrm{SR} \\ & \mathrm{t}_{\mathrm{S}} \\ & \mathrm{FT}_{\mathrm{AC}} \\ & \mathrm{CT}_{\mathrm{AC}} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\text {OUT }}=0.1 \mathrm{~V} \mathrm{rms} \\ & \mathrm{~V}_{\text {OUT }}= \pm 2.5 \mathrm{~V} \\ & \mathrm{~V}_{\text {OUT }}=\Delta 2.5 \mathrm{~V} \text { to } 1 \% \text { Error Band } \\ & \mathrm{X}=0 \mathrm{~V}, \mathrm{Y}=1 \mathrm{~V} \text { rms @ } \mathrm{f}=100 \mathrm{kHz} \\ & \mathrm{X}=\mathrm{Y}=1 \mathrm{~V} \text { rms Applied to Adjacent Channel } \end{aligned}$ | 30 | $\begin{aligned} & 8 \\ & 53 \\ & 1 \\ & -65 \\ & -90 \end{aligned}$ |  | M Hz <br> $\mathrm{V} / \mu \mathrm{s}$ <br> $\mu \mathrm{S}$ <br> dB <br> dB |
| OUTPUTS <br> Audio Band Noise <br> Wide Band N oise <br> Spot N oise V oltage <br> T otal H armonic Distortion <br> Open Loop Output Resistance <br> Voltage Swing <br> Short Circuit Current | $E_{N}$ <br> $E_{N}$ <br> $\mathrm{e}_{\mathrm{N}}$ <br> THD <br> THD <br> $\mathrm{R}_{\text {OUT }}$ <br> $\mathrm{V}_{\text {PK }}$ <br> $\mathrm{I}_{\mathrm{sc}}$ | $\begin{aligned} & \mathrm{f}=10 \mathrm{~Hz} \text { to } 50 \mathrm{kHz} \\ & \mathrm{~N} \text { oise } \mathrm{BW}=1.9 \mathrm{M} \mathrm{~Hz} \\ & \mathrm{f}=1 \mathrm{kHz} \\ & \mathrm{f}=1 \mathrm{kHz}, \mathrm{LPF}=22 \mathrm{kHz}, \mathrm{Y}=2.5 \mathrm{~V} \\ & \mathrm{f}=1 \mathrm{kHz}, \mathrm{LPF}=22 \mathrm{kHz}, \mathrm{X}=2.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5 \mathrm{~V} \end{aligned}$ | $\pm 3.0$ | $\begin{aligned} & 76 \\ & 380 \\ & 0.3 \\ & 0.1 \\ & 0.02 \\ & 40 \\ & \pm 3.3 \\ & 30 \end{aligned}$ |  | $\mu \mathrm{V}$ rms $\mu \mathrm{V}$ rms $\mu \mathrm{V} / \mathrm{VHz}$ \% <br> \% <br> $\Omega$ <br> $V_{p}$ <br> mA |
| INPUTS <br> Analog Input Range Bias C urrent Resistance Capacitance | $\begin{aligned} & \text { IVR } \\ & \mathrm{I}_{\mathrm{B}} \\ & \mathrm{R}_{\text {IN }} \\ & \mathrm{C}_{\text {IN }} \end{aligned}$ | $\begin{aligned} & G N D=0 V \\ & X=Y=0 V \end{aligned}$ | $-2.5$ | $\begin{aligned} & 2.3 \\ & 1 \\ & 3 \end{aligned}$ | $\begin{aligned} & +2.5 \\ & 10 \end{aligned}$ | V <br> $\mu \mathrm{A}$ <br> $M \Omega$ <br> pF |
| SQUARE PERFORMANCE T otal Square Error | $\mathrm{E}_{\text {SQ }}$ | $X=Y=1$ |  | 5 |  | \% FS |
| POWER SUPPLIES <br> Positive C urrent <br> N egative C urrent <br> Power Dissipation <br> Supply Sensitivity <br> Supply Voltage Range | $I_{c c}$ <br> $I_{\text {EE }}$ <br> $P_{\text {DISS }}$ <br> PSSR <br> $V_{\text {range }}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.25 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=5.25 \mathrm{~V}, \mathrm{~V}_{\mathrm{EE}}=-5.25 \mathrm{~V} \\ & \mathrm{C} \text { alculated }=5 \mathrm{~V} \times \mathrm{I}_{\mathrm{CC}}+5 \mathrm{~V} \times \mathrm{I}_{\mathrm{EE}} \\ & \mathrm{X}=\mathrm{Y}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=\Delta 5 \% \text { or } \mathrm{V}_{\mathrm{EE}}=\Delta 5 \% \\ & \text { For } \mathrm{V}_{\mathrm{CC}} \& \mathrm{~V}_{\mathrm{EE}} \end{aligned}$ | $\pm 4.75$ | $\begin{aligned} & 15 \\ & 15 \\ & 150 \end{aligned}$ | $\begin{aligned} & 20 \\ & 20 \\ & 200 \\ & 10 \\ & \pm 5.25 \end{aligned}$ | mA <br> mA <br> mW <br> $\mathrm{mV} / \mathrm{N}$ <br> V |

NOTES
${ }^{1}$ Specifications apply to all four multipliers.
${ }^{2}$ Error is measured as a percent of the $\pm 2.5 \mathrm{~V}$ full scale, i.e., $1 \% \mathrm{FS}=25 \mathrm{mV}$.
${ }^{3}$ Scale F actor K is an internally set constant in the multiplier transfer equation $\mathrm{W}=\mathrm{K} \times \mathrm{X} \times \mathrm{Y}$.
Specifications subject to change without notice.

## ABSOLUTE MAXIMUM RATINGS*

Supply Voltages $\mathrm{V}_{\mathrm{CC}}, \mathrm{V}_{\mathrm{EE}}$ to GND Inputs $X_{1}, Y_{1}$
Outputs W,
O perating T emperature Range
$M$ aximum Junction $T$ emperature ( $T$, max)
Storage T emperature
Lead T emperature (Soldering, 10 sec )
Package Power Dissipation
Thermal Resistance $\theta_{\mathrm{JA}}$
PDIP-18 (N-18)

ORDERING INFORMATION*

| Model | Temperature <br> Range | Package <br> Description | Package <br> Option |
| :--- | :--- | :--- | :--- |
| M LT 04G P | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 18-Pin P-DIP | N-18 |
| M LT 04G S | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 18-Lead SOIC | SOL-18 |
| M LT 04G S-REEL | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 18-Lead SOIC | SOL-18 |
| M LT 04G BC | $+25^{\circ} \mathrm{C}$ | D ie |  |

*F or die specifications contact your local A nalog sales office. The M LT 04 contains 211 transistors.

SOIC-18 (SOL-18)
*Stresses above those listed under "A bsolute $M$ aximum R atings" may cause nent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification are not implied.

$$
\pm 7 \mathrm{~V}
$$

$$
\mathrm{V}_{\mathrm{CC}}, \mathrm{~V}_{\mathrm{EE}}
$$

$$
\begin{array}{r}
\mathrm{V}_{\mathrm{CC}}, \mathrm{~V}_{\text {EE }} \\
-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C}
\end{array}
$$

$$
\begin{array}{r}
+150^{\circ} \mathrm{C} \\
-65^{\circ} \mathrm{C} \text { to }+150^{\circ} \mathrm{C}
\end{array}
$$

$$
+300^{\circ} \mathrm{C}
$$

$$
\left(\mathrm{T}_{\mathrm{j}} \max -\mathrm{T}_{\mathrm{A}}\right) / \theta_{\mathrm{JA}}
$$

$$
74^{\circ} \mathrm{C} / \mathrm{W}
$$ $89^{\circ} \mathrm{C} / \mathrm{W}$

## FUNCTIONAL DESCRIPTION

The M LT 04 is a low cost quad, 4-quadrant analog multiplier with single-ended voltage inputs and voltage outputs. The functional block diagram for each of the multipliers is illustrated in Figure 3. D ue to packaging constraints, access to internal nodes for externally adjusting scale factor, output offset voltage, or additional summing signals is not provided.


Figure 3. Functional Block Diagram of Each MLT04 Multiplier

Each of the M LT 04's analog multipliers is based on a Gilbert cell multiplier configuration, a 1.23 V bandgap reference, and a unityconnected output amplifier. M ultiplier scale factor is determined through a differential pair/trimmable resistor network external to the core. An equivalent circuit for each of the multipliers is shown in Figure 4.


Figure 4. Equivalent Circuit for the MLTO4

D etails of each multiplier's output-stage amplifier are shown in Figure 5. The output stages idles at $200 \mu \mathrm{~A}$, and the resistors in series with the emitters of the output stage are $25 \Omega$. The output stage can drive load capacitances up to 500 pF without oscillation. F or loads greater than 500 pF , the outputs of the M LT 04 should be isolated from the load capacitance with a $100 \Omega$ resistor.


Figure 5. Equivalent Circuit for MLT04 Output Stages

## ANALOG MULTIPLIER ERROR SOURCES

M ultiplier errors consist primarily of input and output offsets, scale factor errors, and nonlinearity in the multiplying core. An expression for the output of a real analog multiplier is given by:

$$
V_{0}=(K+\Delta K)\left\{\left(V_{X}+X_{o s}\right)\left(V_{Y}+Y_{o s}\right)+Z_{o s}+f(X, Y)\right\}
$$

where: $K=$ M ultiplier Scale Factor
$\Delta K=$ Scale Factor Error
$\mathrm{V}_{\mathrm{x}} \quad=\mathrm{X}$-Input Signal
$X_{\text {os }}=X$-Input Offset Voltage
$V_{Y} \quad=Y$-Input Signal
$Y_{o s} \quad=Y$-Input Offset Voltage
$Z_{o s}^{o s}=M$ ultiplier Output Offset Voltage
$f(X, Y)=$ Nonlinearity
Executing the algebra to simplify the above expression yields expressions for all the errors in an analog multiplier:

| Term | Description | Dependence on Input |
| :---: | :---: | :---: |
| $\mathrm{KV}_{\mathrm{x}} \mathrm{V}_{\mathrm{Y}}$ | T rue Product | Goes to Zero As Either or Both Inputs Go to Zero |
| $\Delta K V_{Y} V_{Y}$ | Scale-F actor Error | Goes to Zero at $\mathrm{V}_{\mathrm{X}}, \mathrm{V}_{\mathrm{Y}}=0$ |
| $\mathrm{V}_{\mathrm{x}} \mathrm{Y}_{\text {os }}$ | Linear "X" F eedthrough D ue to $Y$-Input Offset | Proportional to $\mathrm{V}_{\mathrm{x}}$ |
| $V_{Y} \mathrm{X}_{\text {os }}$ | Linear "Y" F eedthrough D ue to X-Input Offset | Proportional to $\mathrm{V}_{Y}$ |
| $\mathrm{X}_{\text {os }} \mathrm{Y}_{\text {os }}$ | Output Offset Due to X-, Y -Input Offsets | Independent of $\mathrm{V}_{\mathrm{x}}, \mathrm{V}_{\mathrm{Y}}$ |
| $Z_{\text {os }}$ | Output Offset | Independent of $\mathrm{V}_{\chi}, \mathrm{V}_{Y}$ |
| $f(X, Y)$ | Nonlinearity | Depends on Both $V_{x}, V_{y}$. C ontains T erms D ependent on $\mathrm{V}_{\mathrm{x}}, \mathrm{V}_{\mathrm{y}}$, Their Powers and Cross Products |

As shown in the table, the primary static errors in an analog multiplier are input offset voltages, output offset voltage, scale factor, and nonlinearity. Of the four sources of error, only two are externally trimmable in the M LT 04: the X - and Y-input offset voltages. O utput offset voltage in the M LT 04 is factory-trimmed to $\pm 50 \mathrm{mV}$, and the scale factor is internally adjusted to $\pm 2.5 \%$ of full scale. Input offset voltage errors can be eliminated by using the optional trim circuit of Figure 6. This scheme then reduces the net error to output offset, scale-factor (gain) error, and an irreducible nonlinearity component in the multiplying core.


Figure 6. Optional Offset Voltage Trim Configuration

## MLT04

## Feedthrough

In the ideal case, the output of the multiplier should be zero if either input is zero. In reality, some portion of the nonzero input will "feedthrough" the multiplier and appear at the output. This is caused by the product of the nonzero input and the offset voltage of the "zero" input. Introducing an offset equal to and opposite of the "zero" input offset voltage will null the linear component of the feedthrough. Residual feedthrough at the output of the multiplier is then irreducible core nonlinearity.
Typical X - and Y-input feedthrough curves for the M LT 04 are shown in Figures 7 and 8, respectively. These curves illustrate M LT 04 feedthrough after "zero" input offset voltage trim. Residual $X$-input feedthrough measures $0.08 \%$ of full scale, whereas residual Y -input feedthrough is almost immeasurable.


Figure 7. $X$-Input Feedthrough with $Y_{\text {os }}$ Nulled


HORIZONTAL - 0.5V/DIV
Figure 8. $Y$-Input Feedthrough with $X_{o s}$ Nulled

## Nonlinearity

M ultiplier core nonlinearity is the irreducible component of error. It is the difference between actual performance and "best-straightline" theoretical output, for all pairs of input values. It is expressed as a percentage of full scale with all other dc errors nulled. Typical $X$ - and $Y$-input nonlinearities for the M LT 04 are shown in Figures 9 through 12. Worst-case $X$-input nonlinearity measured less than $0.2 \%$, and $Y$-input nonlinearity measured better than $0.06 \%$. F or modulator/demodulator or mixer applications it is, therefore, recommended that the carrier be connected to the $X$-input while the signal is applied to the $Y$-input.


Figure 9. $X$-Input Nonlinearity @ $Y=+2.5 \mathrm{~V}$


Figure 10. $X$-Input Nonlinearity @ $Y=-2.5 \mathrm{~V}$


Figure 11. $Y$-Input Nonlinearity @ $X=+2.5$ V


Figure 12. $Y$-Input Nonlinearity @ $X=-2.5$ V

## Typical Performance Characteristics - MLT04



Figure 13. Broadband Noise


Figure 14. Broadband Noise


Figure 15. Noise Density vs. Frequency


Figure 16. X-Input Gain and Phase vs. Frequency


Figure 17. Y-Input Gain and Phase vs. Frequency


Figure 18. Amplitude Response vs. Capacitive Load

## MLT04 - Typical Performance Characteristics



Figure 19. Feedthrough vs. Frequency


Figure 20. Crosstalk vs. Frequency


Figure 21. Gain Flatness vs. Frequency


Figure 22. Y-Input Small-Signal Transient Response, $C_{L}=30 \mathrm{pF}$


Figure 23. Y-Input Small-Signal Transient Response, $C_{L}=100 \mathrm{pF}$


Figure 24. $Y$-Input Large-Signal Transient Response, $C_{L}=30 \mathrm{pF}$


Figure 25. Y-Input Large-Signal Transient Response, $C_{L}=100 \mathrm{pF}$


Figure 26. THD + Noise vs. Input Signal Level


Figure 27. Linearity Error vs. Temperature


Figure 28. X-Input Gain Bandwidth vs. Temperature


Figure 29. Y-Input Gain Bandwidth vs. Temperature


Figure 30. Maximum Output Swing vs. Frequency


Figure 31. Maximum Output Swing vs. Resistive Load


Figure 32. Offset Voltage Distribution


Figure 33. Offset Voltage vs. Temperature


Figure 34. Scale Factor Distribution


Figure 35. Scale Factor vs. Temperature


Figure 36. Output Offset Voltage $\left(Z_{o s}\right)$ Distribution


Figure 37. Output Offset Voltage $\left(Z_{o s}\right)$ vs. Temperature


Figure 38. Supply Current vs. Temperature


Figure 39. Power Supply Rejection vs. Frequency


Figure 40. Linearity Error (LE) Distribution Accelerated by Burn-in


Figure 41. Output Voltage Offset $\left(Z_{o S}\right)$ Distribution Accelerated by Burn-in


Figure 42. Scale Factor (K) Distribution Accelerated by Burn-in

## APPLICATIONS

T he M LT 04 is well suited for such applications as modulation/ demodulation, automatic gain control, power measurement, analog computation, voltage-controlled amplifiers, frequency doublers, and geometry correction in CRT displays.

## Multiplier Connections

Figure 43 llustrates the basic connections for multiplication. Each of the four independent multipliers has single-ended voltage inputs ( $\mathrm{X}, \mathrm{Y}$ ) and a low impedance voltage output (W). Also, each multiplier has its own dedicated ground connection (GND) which is connected to the circuit's analog common. F or best performance, circuit layout should be compact with short component leads and well-bypassed supply voltage feeds. In applications where fewer than four multipliers are used, all unused analog inputs must be returned to the analog common.


Figure 43. Basic Multiplier Connections

## Squaring and Frequency Doubling

As shown in Figure 44, squaring of an input signal, $\mathrm{V}_{\text {IN }}$, is achieved by connecting the X -and Y -inputs in parallel to produce an output of $\mathrm{V}_{\text {IN }}{ }^{2} / 2.5 \mathrm{~V}$. The input may have either polarity, but the output will be positive.


Figure 44. Connections for Squaring
When the input is a sine wave given by $\mathrm{V}_{\text {IN }} \sin \omega t$, the squaring circuit behaves as a frequency doubler because of the trigonometric identity:

$$
\frac{\left(\mathrm{V}_{\mathrm{IN}} \sin \omega \mathrm{t}\right)^{2}}{2.5 \mathrm{~V}}=\frac{\mathrm{V}_{\mathrm{IN}}{ }^{2}}{2.5 \mathrm{~V}}\left(\frac{1}{2}\right)(1-\cos 2 \omega t)
$$

The equation shows a dc term at the output which will vary strongly with the amplitude of the input, $\mathrm{V}_{\mathrm{IN}}$. The output dc offset can be eliminated by capacitively coupling the M LT 04's output with a high-pass filter. For optimal spectral performance, the filter's cutoff frequency should be chosen to eliminate the input fundamental frequency.
A source of error in this configuration is the offset voltages of the $X$ and $Y$ inputs. The input offset voltages produce cross products with the input signal to distort the output waveform. To circumvent this problem, Figure 45 illustrates the use of inverting amplifiers configured with an OP285 to provide a means by which the $X$ - and $Y$-input offsets can be trimmed.


Figure 45. Frequency Doubler with Input Offset Voltage Trims

## Feedback Divider Connections

The most commonly used analog divider circuit is the "inverted multiplier" configuration. As illustrated in Figure 46, an "inverted multiplier" analog divider can be configured with a multiplier operating in the feedback loop of an operational amplifier. The general form of the transfer function for this circuit configuration is given by:

$$
V_{0}=-2.5 \mathrm{~V} \times\left(\frac{R 2}{R 1}\right) \times \frac{V_{I N}}{V_{X}}
$$

Here, the multiplier operates as a voltage-controlled potentiometer that adjusts the loop gain of the op amp relative to a control signal, $\mathrm{V}_{x}$. As the control signal to the multiplier decreases, the output of the multiplier decreases as well. This has the effect of reducing negative feedback which, in turn, decreases the amplifier's loop gain. The result is higher closed-loop gain and reduced circuit bandwidth. As $\mathrm{V}_{\mathrm{x}}$ is increased, the output of the multiplier increases which generates more negative feedback - closed-loop gain drops and circuit bandwidth increases. An example of an "inverted multiplier" analog divider frequency response is shown in Figure 47.

$\mathrm{V}_{\mathrm{O}}=-2.5 \mathrm{~V} \cdot \frac{\mathrm{~V}_{\mathrm{IN}}}{\mathrm{V}_{\mathrm{X}}}$

Figure 46. "Inverted-Multiplier" Configuration for Analog Division


Figure 47. Signal-Dependent Feedback Makes Variables Out of Amplifier Bandwidth and Stability

Although this technique works well with almost any operational amplifier, there is one caveat: for best circuit stability, the unitygain crossover frequency of the operational amplifier should be equal to or less than the M LT 04's 8 M Hz bandwidth.

## Connection for Square Rooting

A nother application of the "inverted multiplier" configuration is the square-root function. As shown in Figure 48, both inputs of the M LT 04 are wired together and are used as the output of the circuit. Because the circuit configuration exhibits the following generalized transfer function:

$$
V_{0}=\sqrt{-2.5 \times\left(\frac{\mathrm{R} 2}{\mathrm{R} 1}\right) \times \mathrm{V}_{\mathrm{IN}}}
$$

the input signal voltage is limited to the range $-2.5 \mathrm{~V} \leq \mathrm{V}_{\text {IN }}<0$. To prevent circuit latchup due to positive feedback or input signal polarity reversal, a 1N 4148-type junction diode is used in series with the output of the multiplier.

Figure 48. Connections for Square Rooting


## Voltage-Controlled Low-Pass Filter

The circuit in Figure 49 illustrates how to construct a voltagecontrolled low-pass filter with an analog multiplier. T he advantage with this approach over conventional active-filter configurations is that the overall characteristic cut-off frequency, $\omega_{0}$, will be directly proportional to a multiplying input voltage. This permits the construction of filters in which the capacitors are adjustable (directly or inversely) by a control voltage. Hence, the frequency scale of a filter can be manipulated by means of a single voltage without affecting any other parameters. The general form of the circuit's transfer function is given by:

$$
\frac{V_{0}}{V_{I N}}=-\left(\frac{R 2}{R 1}\right)\left\{\frac{1}{s\left(\frac{R 2+R 1}{R 1}\right)\left(\frac{2.5 R C}{V_{x}}\right)+1}\right\}
$$

In this circuit, the ratio of R2 to R1 sets the passband gain, and the break frequency of the filter, $\omega_{\mathrm{Lp}}$, is given by:

$$
\omega_{L P}=\left(\frac{R 1}{R 1+R 2}\right)\left(\frac{V_{x}}{2.5 R C}\right)
$$



Figure 49. A Voltage-Controlled Low-Pass Filter For example, if $\mathrm{R} 1=\mathrm{R} 2=10 \mathrm{k} \Omega, \mathrm{R}=10 \mathrm{k} \Omega$, and $\mathrm{C}=80 \mathrm{pF}$,

## MLT04

then the output of the circuit has a pole at frequencies from 1 kHz to 100 kHz for $\mathrm{V}_{\mathrm{x}}$ ranging from 25 mV to 2.5 V . The performance of this low-pass filter is illustrated in Figure 20.


Figure 50. Low-Pass Cutoff Frequency vs. Control Voltage, $V_{x}$

With this approach, it is possible to construct parametric biquad filters whose parameters (center frequency, passband gain, and Q) can be adjusted with dc control voltages.

## OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

## 18-Lead Epoxy DIP (P Suffix)



18-Lead Wide-Body SOL (S Suffix)


